

OBSOLETE:

FOR INFORMATION PURPOSES ONLY

Contact Linear Technology for Potential Replacement

FEATURES

- Direct Replacement for Present References
- Ultra Low Drift—3ppm/°C Typ.
- Curvature Corrected
- Series or Shunt Operation
- Ultra High Line Rejection $\approx 1/2$ ppm/V
- Low Output Impedance $\approx 0.02\Omega$
- Tight Initial Output Voltage
- 100% Noise Tested

APPLICATIONS

- A to D and D to A Converters
- Precision Regulators
- Constant Current Sources
- V to F Converters
- Bridge Excitation

DESCRIPTION

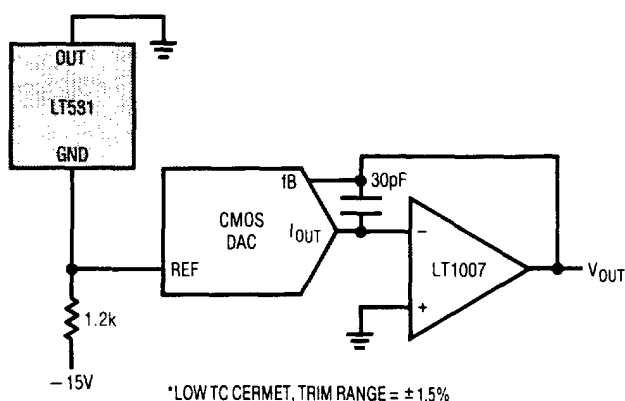
The LT580/LT581 are bandgap voltage references utilizing thin film technology and a greatly improved curvature correction technique. Wafer level trimming of both reference and output voltage combines to produce units with high yields to very low TC and tight initial tolerance of output voltage.

The LT580/LT581 can both sink and source up to 10mA and can be used in either the series or shunt mode. This allows the reference to be used for both positive and negative output voltages without external components. Minimum input-output voltage is less than 1V in the series mode, providing improved tolerance of low line conditions.

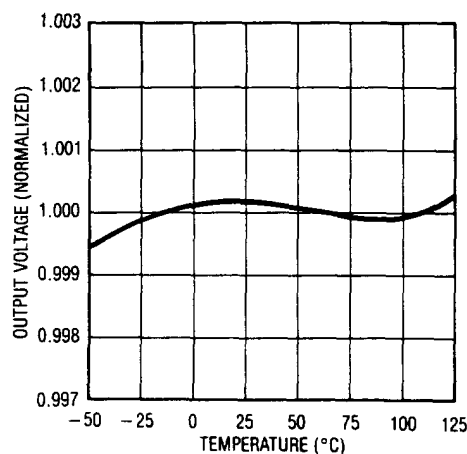
For voltage references with improved specifications, please see the LT1019, LT1021, and LT1031 data sheets.

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Negative 10V Reference for CMOS DAC



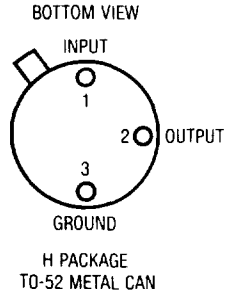
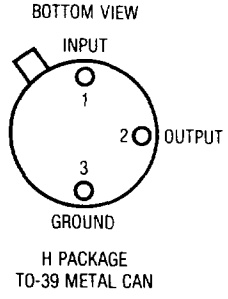
Output Voltage Drift



ABSOLUTE MAXIMUM RATINGS

Input Voltage	40V
Storage Temperature Range	– 65°C to 175°C
Lead Temperature (Soldering, 10 sec.)	300°C
Operating Temperature Range	
J, K, L, M Grades	0°C to 70°C
S, T, U Grades	– 55°C to 125°C

PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER
	LT580JH LT580KH LT580LH LT580MH LT580SH LT580TH LT580UH
	LT581JH LT581KH LT581LH LT581SH LT581TH LT581UH

LT580 ELECTRICAL CHARACTERISTICS $V_{IN} = +15V$, $T_A = 25^\circ C$ unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	MIN	LT580 TYP	MAX	UNITS
V_R	Output Voltage	LT580J	2.425	2.500	2.575	V
		LT580K, S	2.475	2.500	2.525	V
		LT580L, M, T, U	2.490	2.500	2.510	V
TC	Output Voltage Change Over Temperature in mV and (ppm/°C)	LT580J (0°C to 70°C)	●		15 (85)	mV (ppm/°C)
		LT580K (0°C to 70°C)	●		7 (40)	mV (ppm/°C)
		LT580L (0°C to 70°C)	●		4.3 (25)	mV (ppm/°C)
		LT580M (0°C to 70°C)	●		1.75 (10)	mV (ppm/°C)
		LT580S (– 55°C to + 125°C)	●		25 (55)	mV (ppm/°C)
		LT580T (– 55°C to + 125°C)	●		11 (25)	mV (ppm/°C)
		LT580U (– 55°C to + 125°C)	●		4.5 (10)	mV (ppm/°C)
$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	Line Regulation	7V ≤ V_{IN} ≤ 30V		0.5	6	mV
		LT580J, S		0.5	4	mV
		LT580K		0.5	2	mV
		LT580L, M, T, U		0.1	3	mV
		4.5V ≤ V_{IN} ≤ 7V		0.1	2	mV
		LT580J, S		0.1	1	mV
$\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$	Load Regulation (Sourcing) Shunt Mode	0 ≤ I_{OUT} ≤ 10mA		1	10	mV
		1.5mA ≤ I_{SHUNT} ≤ 10mA		2	10	mV
I_Q	Quiescent Current			0.75	1.5	mA
e_n	Output Noise (Note 1)	0.1Hz to 10Hz		10		μVp-p
	Output Voltage Stability with Time	Per Month Long Term		25 250		μV μV

LT581 ELECTRICAL CHARACTERISTICS $V_{IN} = +15V$, $T_A = 25^\circ C$ unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	MIN	LT581 TYP	MAX	UNITS
V_R	Output Voltage	LT581S, J	9.970	10.000	10.030	V
		LT581T, K	9.990	10.000	10.010	V
		LT581U, L	9.995	10.000	10.005	V
TC	Output Voltage Change, Maximum Deviation from $25^\circ C$ in mV and (ppm/ $^\circ C$)	LT581J ($0^\circ C$ to $70^\circ C$)	•		13.5 (30)	mV (ppm/ $^\circ C$)
		LT581K ($0^\circ C$ to $70^\circ C$)	•		6.75 (15)	mV (ppm/ $^\circ C$)
		LT581L ($0^\circ C$ to $70^\circ C$)	•		2.25 (5)	mV (ppm/ $^\circ C$)
		LT581S ($-55^\circ C$ to $+125^\circ C$)	•		30 (30)	mV (ppm/ $^\circ C$)
		LT581T ($-55^\circ C$ to $+125^\circ C$)	•		15 (15)	mV (ppm/ $^\circ C$)
		LT581U ($-55^\circ C$ to $+125^\circ C$)	•		10 (10)	mV (ppm/ $^\circ C$)
$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	Line Regulation	$15V \leq V_{IN} \leq 30V$		0.5	3	mV
		$13V \leq V_{IN} \leq 15V$		0.1	1	mV
$\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$	Load Regulation (Sourcing) Shunt Mode	$0 \leq I_{OUT} \leq 5mA$		50	500	$\mu V/mA$
		$1mA \leq I_{SHUNT} \leq 5mA$		100	500	$\mu V/mA$
I_Q	Quiescent Current			0.75	1.0	mA
e_n	Output Noise (Note 1)	0.1Hz to 10Hz		30		$\mu Vp-p$
	Long Term Stability	Non-Cumulative		25		ppm/kHr
I_{SC}	Short Circuit Current			30		mA
I_{OUT}	Output Current	Sourcing	10	25		mA
		Sourcing	5			mA
		Sinking	5			mA

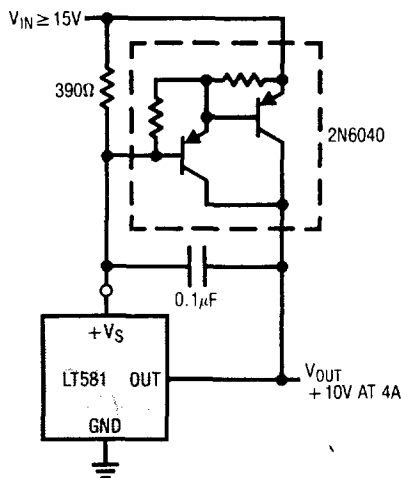
The • denotes the specifications which apply over the full operating temperature range.

Note 1: Although 0.1Hz to 10Hz noise is not a standard production test, Linear Technology does 100% test 10Hz to 1kHz noise. Consult factory for details.

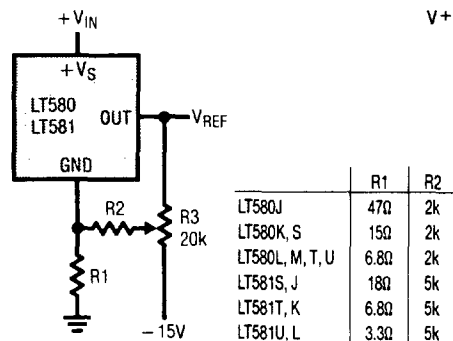
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TYPICAL APPLICATIONS

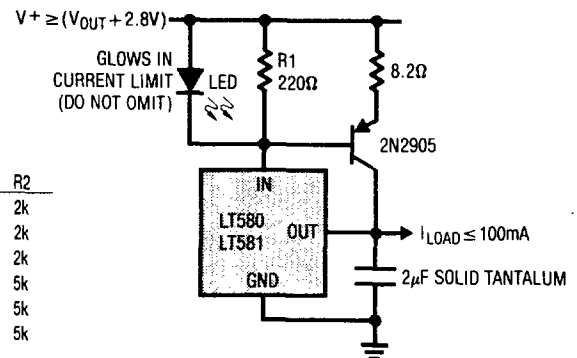
High Current Precision Supply



Suggested Output Trim

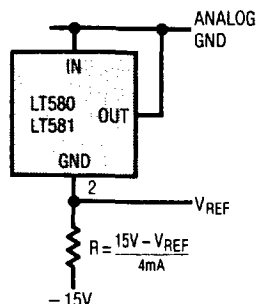


Output Current Boost with Current Limit

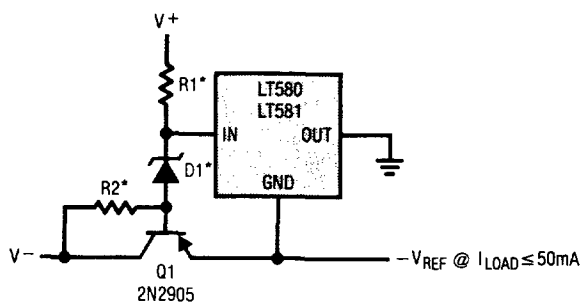


TYPICAL APPLICATIONS

Two-Terminal Negative Reference

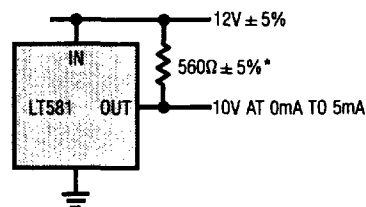


Negative Series Reference



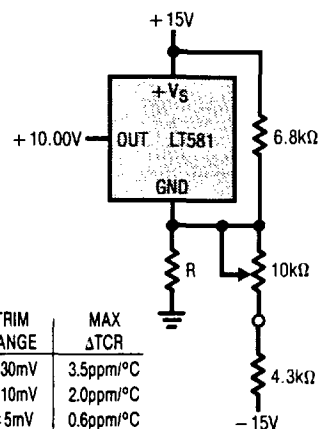
$$R1 = \frac{V+ - 5V}{2mA}, R2 = \frac{|V-| - VREF}{1mA}, D1 = VREF + 5V$$

12V Supply Connection



*NOT REQUIRED ON LTC LT580 OR LT581

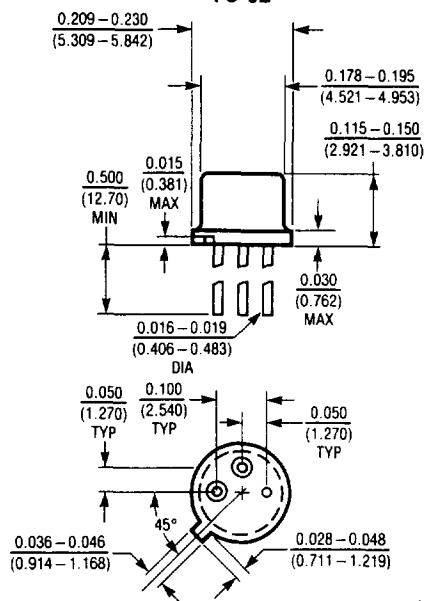
Optional Trim Configuration



R	TRIM RANGE	MAX ΔTCR
22Ω	±30mV	3.5ppm/°C
12Ω	±10mV	2.0ppm/°C
3.9Ω	±5mV	0.6ppm/°C

PACKAGE DESCRIPTION

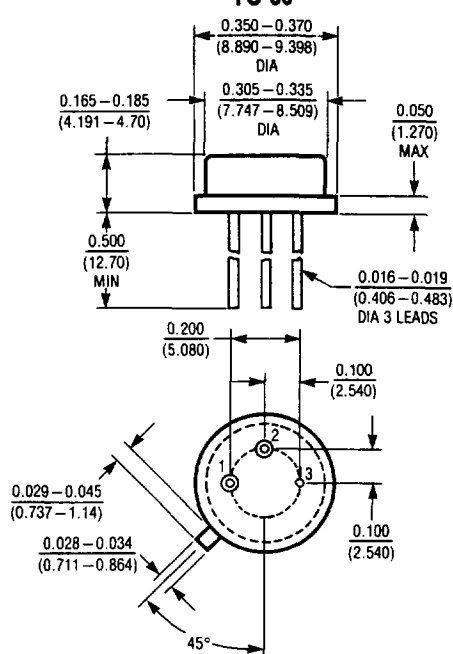
LT580 TO-52



H3(52)188

Tjmax	θJA
150°C	360°C/W

LT581 TO-39



H3(39)188

Tjmax	θJA
150°C	150°C/W